

## Supplementary Material

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# Micro-mirror aided mid-infrared plasmonic beam combiner monolithically integrated with quantum cascade lasers and detectors

## 1 Supplementary Material

### 1.1 Cutback Technique and Measurement Approach

To characterize optical losses, we used a method similar to the standard cutback technique. In traditional cutback, waveguides (WGs) are progressively shortened and measured at each length, allowing WG and coupling losses to be derived from a linear fit of the total measured losses as a function of inverse device length. In this study, we fabricated multiple WGs of varying lengths on the same chip and characterized them individually. This method, assuming consistent optical properties across WGs, yields comparable results to the standard cutback technique [1]. A calibration sample without a Ge-WG was fabricated to normalize the measurements. The sample, featuring a directly butt-coupled QCD and external QCL, had an air gap of approximately 2  $\mu\text{m}$ . The losses attributed to the micro-mirrors ( $\alpha_M$ ) were calculated by subtract-

ing the coupling losses ( $\alpha_c = 7.2 \text{ dB}$ ) and the waveguide losses ( $\alpha_{wg} = 0.018 \text{ dB}/\mu\text{m}$ ) from the total measured losses ( $\alpha_{tot}$ ) of the structures employing mirrors. Figure 7 in the manuscript shows the mean values of linear WG devices for various lengths, with blue diamonds representing the reference configuration without additional mode redirection. A linear fit to the data (black dotted line) reveals waveguide losses ( $\alpha_{wg}$ ) of  $0.018 \text{ dB}/\mu\text{m}$ , while coupling losses ( $\alpha_c$ ) were determined to be  $7.2 \text{ dB}$  from the zero offset of the line. Variations in emitted wavelengths from the QCL devices (between 8 and  $8.3 \mu\text{m}$ ) due to the absence of wavelength locking were accounted for in the simulations, as seen by the widening purple cone in the plot. Colored data points correspond to designs incorporating integrated gold micro-mirrors for mode redirection. To quantitatively assess and compare losses from different micro-mirror designs, the total measured losses ( $\alpha_{tot}$ ) were adjusted by subtracting coupling and waveguide losses. The resulting mirror losses were calculated as follows:

$$\overline{\alpha_M} = \frac{1}{n} \sum_{i=1}^n \alpha_{tot_n} - \alpha_{wg} - \alpha_c$$

where  $n$  is the number of measured devices. Figure 7 in the manuscript illustrates  $\alpha_{tot} - \overline{\alpha_M}$  alongside the standard deviation of  $\alpha_{tot}$  at corresponding waveguide lengths. Different waveguide lengths for single and double mirror configurations stem from various design versions. Experimental results show that the mirror losses for the single-mirror configuration are about 5 dB higher than in simulations, likely due to fabrication imperfections such as non-fully vertical reflection planes of the gold layer, leading to increased reflection losses.

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## References

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